

isc Silicon PNP Darlington Power Transistor

2SB1344

DESCRIPTION

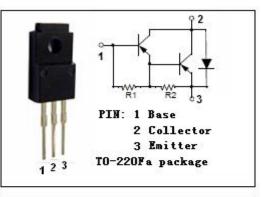
- Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -100V(Min)
- High DC Current Gain-
- : h_{FE}= 1000(Min)@ (V_{CE}= -3V, I_C= -2A)
- Complement to Type 2SD2025
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

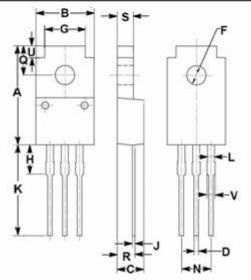
APPLICATIONS

• Designed for power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{СВО}	Collector-Base Voltage	-100	V	
V _{CEO}	Collector-Emitter Voltage	-100	V	
V _{EBO}	Emitter-Base Voltage	-7	V	
lc	Collector Current-Continuous	-8	А	
I _{CM}	Collector Current-Peak	-10	A	
Pc	Collector Power Dissipation @Ta=25℃	2	W	
	Collector Power Dissipation @Tc=25℃	30	vv	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	





	mm	
DIM	MIN	MAX
Α	16.85	17.15
В	9.54	10.10
С	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
Н	5.15	5.45
J	0.45	0.75
K	13.35	13.65
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
V	1.30	1.50

isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

Tj=25° \mathbb{C} unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA; I _B = 0	-100			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = -50 μ A; I _E = 0	-100			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -3A; I _B = -6mA			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -100V; I _E = 0			-10	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-3	mA
h _{FE}	DC Current Gain	I _C = -2A; V _{CE} = -3V	1000		20000	
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f _{test} = 1MHz		90		pF
f⊤	Current-Gain—Bandwidth Product	I _E = 0.5A; V _{CE} = -5V; f _{test} = 10MHz		12		MHz

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